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Vishay Semiconductors

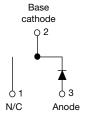
Ultrafast Rectifier, 8 A FRED Pt®

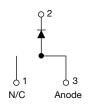




TO-263AB (D²PAK)

TO-262AA





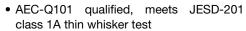
VS-MURB820HM3

VS-MURB820-1HM3

PRODUCT SUMMARY					
Package	TO-263AB (D ² PAK), TO-262AA				
I _{F(AV)}	8 A				
V_{R}	200 V				
V _F at I _F	0.75 V				
t _{rr}	35 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C



 Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>





ROHS COMPLIANT HALOGEN FREE

DESCRIPTION / APPLICATIONS

MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage	V _{RRM}		200	V		
Average rectified forward current	I _{F(AV)}	Total device, rated V _R , T _C = 150 °C	8			
Non-repetitive peak surge current	I _{FSM}		100	Α		
Peak repetitive forward current	I _{FM}	Rated V _R , square wave, 20 kHz, T _C = 150 °C	16			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	200	-	-	
Forward voltage	V	I _F = 8 A	-	0.92	0.975	V
Forward voltage	V _F	I _F = 8 A, T _J = 150 °C	-	0.75	0.895	
Reverse leakage current	1	V _R = V _R rated	-	-	5	
neverse leakage current	I _R	T _J = 150 °C, V _R = V _R rated	-	-	250	μA
Junction capacitance	C _T	V _R = 200 V	-	25	=	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time		I _F = 1.0 A, dI _F /dt = 50	A/µs, V _R = 30 V	-	-	35	
		I _F = 0.5 A, I _R = 1.0 A, I _{REC} = 0.25 A		-	-	25	
	t _{rr}	T _J = 25 °C	I _F = 8 A	-	20	-	ns
		T _J = 125 °C		-	34	-	
Deal was a summer		T _J = 25 °C		-	1.7	-	
Peak recovery current I _{RR}	I _{RRM} T _J = 125 °C		dl _F /dt = 200 A/μs V _R = 160 V	-	4.2	-	A
Reverse recovery charge	0	T _J = 25 °C		-	23	-	nC
	Q _{rr}	T _J = 125 °C		-	75	-	

THERMAL - MECHAN	THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	3.0		
Thermal resistance, junction to ambient	R _{thJA}		-	-	50	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Maight			-	2.0	-	g	
Weight			-	0.07	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-263AB (D ² PAK)	MURB820H				
I Marking device		Case style TO-262AA	MURB820-1H				

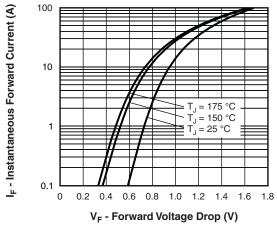


Fig. 1 - Typical Forward Voltage Drop Characteristics

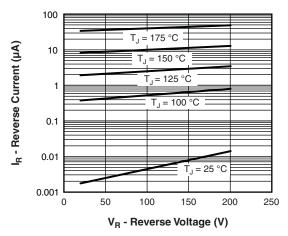


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

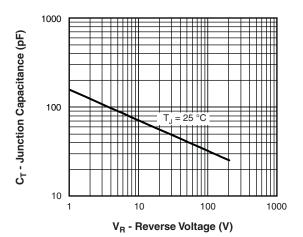


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

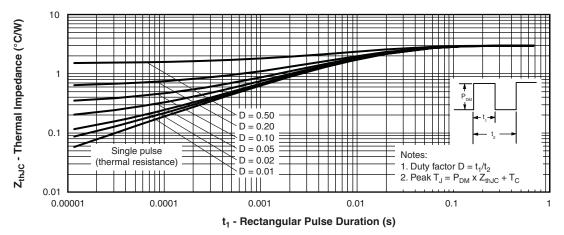


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

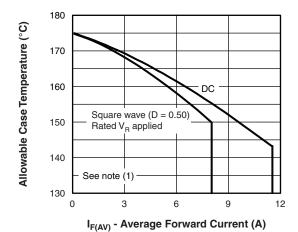


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

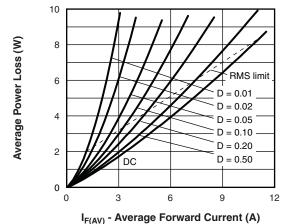


Fig. 6 - Forward Power Loss Characteristics

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

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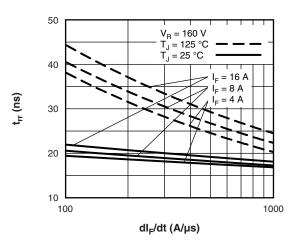


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

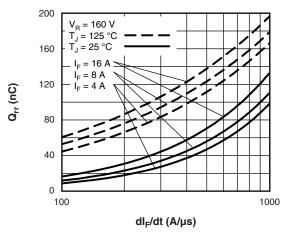
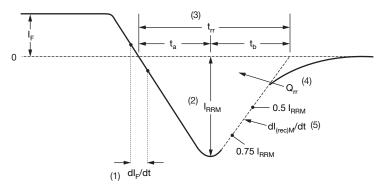


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and l_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

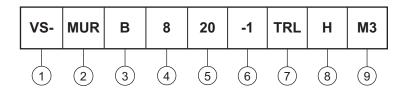
Fig. 9 - Reverse Recovery Waveform and Definitions

VS-MURB820HM3, VS-MURB820-1HM3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Ultrafast MUR series

Current rating (8 = 8 A)

Voltage rating (20 = 200 V)

| 6 | - • None = D^2PAK

• -1 = TO-262

7 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented, for D²PAK package only)

• TRR = tape and reel (right oriented, for D²PAK package only)

8 - H = AEC-Q101 qualified

9 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

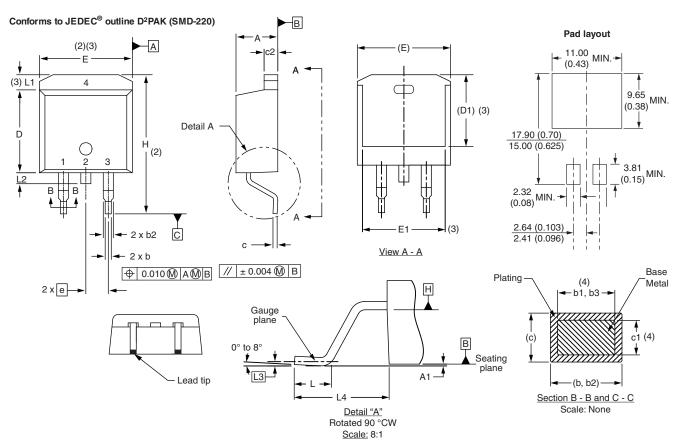
ORDERING INFORMATION						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-MURB820HM3	50	1000	Antistatic plastic tube			
VS-MURB820TRRHM3	800	800	13" diameter reel			
VS-MURB820TRLHM3	800	800	13" diameter reel			
VS-MURB820-1HM3	50	1000	Antistatic plastic tube			

	LINKS TO RELATED DOCUMENTS					
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046				
Dimensions	TO-262AA	www.vishay.com/doc?95419				
Part marking information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?95032				



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

Notes

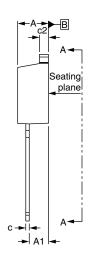
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

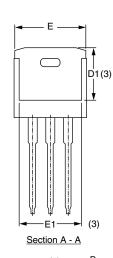


TO-262

DIMENSIONS in millimeters and inches

Modified JEDEC outline TO-262 (Datum A)—(2) (3) (3) L1 D D L2 B B B B L (2) 3 x b2 3 x b2 3 x b2



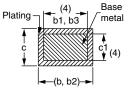


♦0.010**M**|**AM**|**B**|

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

CYMPOL	MILLIN	METERS	INC	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.100	BSC		
L	13.46	14.10	0.530	0.555		
L1	=	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

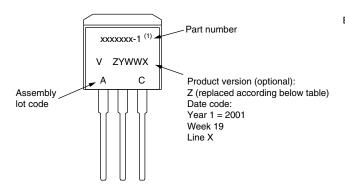
- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



Part Marking Information

Vishay Semiconductors

TO-262



Example: This is a xxxxxxx-1 ⁽¹⁾ with assembly lot code AC, assembled on WW 19, 2001

in the assembly line "X"

Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

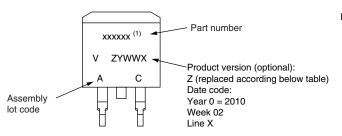
ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION		
A	Termination lead (Pb)-free		
В	Totally lead (Pb)-free		
E	RoHS-compliant and termination lead (Pb)-free		
F	RoHS-compliant and totally lead (Pb)-free		
М	Halogen-free, RoHS-compliant and termination lead (Pb)-free		
N	Halogen-free, RoHS-compliant and totally lead (Pb)-free		
G Green			



Part Marking Information

Vishay Semiconductors

D²PAK



Example: This is a xxxxxx ⁽¹⁾ with assembly lot code AC, assembled on WW 02, 2010

Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION		
A Termination lead (Pb)-free			
B Totally lead (Pb)-free			
E	RoHS-compliant and termination lead (Pb)-free		
F	RoHS-compliant and totally lead (Pb)-free		
M	Halogen-free, RoHS-compliant, and termination lead (Pb)-free		
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free		
G	Green		



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